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## \*BIBDATASHEET\*

Bib Data Sheet

**CONFIRMATION NO. 6907** 

| DID Data CC.   |   |                                   |   |               |     |                 |                       |        |   |  |
|--|---|-----------------------------------|---|---------------|-----|-----------------|-----------------------|--------|---|--|
| SERIAL NUMB<br>10/736,853  |   | FILING DATE<br>12/16/2003<br>RULE | ( | CLASS<br>257  | GRC | OUP ART<br>2829 | JP ART UNIT<br>2829   |        | ATTORNEY<br>DOCKET NO.<br>SC12765TP P01 |  |
| APPLICANTS   |   |                                   |   |               |     |                 |                       |        |   |  |
| Gregory S. Spencer, Pflugerville, TX;  |   |                                   |   |               |     |                 |                       |        |   |  |
| Michael D. Turner, San Antonio, TX;  |   |                                   |   |               |     |                 |                       |        |   |  |
| ** CONTINUING DATA **********************************  |   |                                   |   |               |     |                 |                       |        |   |  |
| Foreign Priority claimed  yes  no  |   |                                   |   | STATE OR      | SH  | EETS            | ТОТ                   | AL     | INDEPENDENT                             |  |
| 35 USC 119 (a-d) conditions  yes  no  Met after met  Verified and  Acknowledged  Examiner's Signature  Initials                  |   |                                   |   | COUNTRY<br>TX | DRA | AWING<br>3      | CLAII<br>22           | MS     | CLAIMS<br>4                             |  |
| ADDRESS<br>23125<br>FREESCALE SEMICONDUCTOR, INC.<br>LAW DEPARTMENT<br>7700 WEST PARMER LANE MD:TX32/PL02<br>AUSTIN, TX<br>78729 |   |                                   |   |               |     |                 |                       |        |   |  |
| TITLE  Method of making a semiconductor device having a low K dielectric   |   |                                   |   |               |     |                 |                       |        |   |  |
|  | ☐ All Fees  |                                   |   |               |     |                 |                       |        |   |  |
|  | FEES: Authority has been given in Paper               |                                   |   |               |     |                 | 6 Fees (              | Filing | 1)                                      |  |
|  | No to charge/credit DEPOSIT ACCOUNT No for following: |                                   |   |               |     |                 |                       |        | essing Ext. of                          |  |
| RECEIVED   |   |                                   |   |               |     |                 | ☐ 1.18 Fees ( Issue ) |        |   |  |
|  |   |                                   |   |               |     |                 |                       |        |   |  |